Introducing a 3 × 3 mm QFN Style Fully Integrated Linear Current Sensor IC

The Allegro™ smallest linear current sensor IC, the ACS711, is housed in a 0.75 mm thick low profile QFN package measuring only 3 mm × 3 mm! (For size comparison see figure 1.) It is designed for low-side or <100 V sensing applications and can sense up to 30 A continuous current, providing a micro-sized package with big performance. This sensor is ideal for replacing sense resistor op-amp current sensing configurations.

Packaging
The sensor IC employs Allegro patented flip-chip technology, illustrated in figure 2, that greatly improves magnetic coupling and allows the compact sensing solution. Current flows in and out of the package through the primary conductor loop. This current generates a magnetic signal that is sensed by the Hall transducer, shown as the red square in figure 2, and is converted to a voltage. The voltage is dependent on the direction of the current flow and so bi-directional current flow of both AC and DC currents is possible using this Hall effect current sensor. The transducer is placed in the area of highest flux density to optimize the magnetic coupling. The Allegro patented flip-chip technology also allows the active area of the transducer to be in closer proximity to the conductor, which further optimizes the signal coupling because the active area of the Hall transducer is on the surface of the silicon closest to the primary conductor.

Soldering and Thermal Characteristics
The QFN configuration conductor resistance is only 0.6 mΩ, which is an order of magnitude smaller than most sense resistors employed in low-side sensing configurations. This saves power consumption in customer applications and provides a higher efficiency and more eco-friendly current sensing solution. The small footprint also saves PCB area, thereby reducing overall system cost. To optimize the advantage of the small primary current path resistance and maximize the amount of continuous current that can flow
through the Allegro package, conducting heat away from the
device must be considered. Figure 3 illustrates an optimized PCB
layout for the QFN package.

For peak thermal and electrical performance, the following fea-
tures should be included in the PCB layout:

- Primary current leads should be connected to as much surface
  area of copper as is reasonably available. The two solder pads at
  the ends of the exposed pad loop should be placed directly on the
  current carrying copper trace to best conduct heat away from the
  package, and is clearly illustrated in figure 3.
- The copper thickness should be 4 oz. Using 2 oz. copper will
  reduce performance.
- If possible, additional copper layers, or at least two layers,
  should be used for conducting the primary current. The lay-
  ers should be connected using the arrangement of vias shown
  in figure 3 and placed close to the primary current leads of the
  QFN package.
- Vias under the exposed QFN pads are excellent for conducting
  heat away from the package, but these vias must be plugged in
  order to prevent wicking of the solder from the pad into the via
  during reflow. Care must be taken when using these types of vias
  and size, quantity, and placement should be considered based on
  the application.

By applying these features, it is possible to achieve the thermal
performance shown in figure 4. The data was taken using a test
demonstration board with a solder footprint similar to the one
shown in figure 3, and using two layers of 4 oz. copper. The
graph shows that at an ambient temperature of 85°C the sensor
package can withstand 45 A continuous current before reaching
the maximum recommended thermal junction (die) temperature
of 165°C. With proper PCB design, the device can be safely used
in 30 A continuous current applications up to 85°C ambient tem-
perature with greater than 40°C of safety margin before reaching
a die temperature of 165°C.

![Figure 3. PCB Layout for QFN Current Sensor](image-url)
**Device Accuracy and Fault Output**
Sense resistor op-amp solutions suffer accuracy error as the sense resistor changes with temperature. Since the magnetic field generated by current flowing in a conductor is not temperature dependent, Hall sensors are not subject to this error term. In addition, the fully integrated architecture of the ACS711 sensor IC allows the major error terms, both gain and offset, to be programmed at end-of-line production to produce a more accurate Hall-effect current sensing solution that is easy for designers to employ in the application.

The ACS711 sensor IC also integrates a factory-programmed fast response digital fault output that has a 1.3 μs response time. This fast fault can be used to prevent the destruction of IGBTs or other switching devices during short circuit or overcurrent conditions, or as a redundant fault feature in motor control applications.

**Summary**
Advanced Allegro patented flip-chip packaging for linear Hall ICs has allowed the creation of a micro-sized, 3 mm × 3 mm fully integrated current sensor device, the Allegro MicroSystems ACS711, which has only a 0.6 mΩ internal resistance, produced in a package that can really take the heat. Used with an appropriate PCB design, the device can be used for applications with over 30 A continuous current while reducing power consumption by an order of magnitude in comparison with existing sense resistor op-amp solutions.

Factory programming provides high accuracy in this IC, with an integrated fast response fault output. Together these techniques deliver the smallest current sensing footprint available for your application without compromising accuracy.